

## Backlighting LEDs in ø 3 mm Tinted Non Diffused Packages

Color	Type	Technology	Angle of half intensity $\pm\varphi$
High efficiency red	TLVH4200	GaAsP on GaP	85°
Yellow	TLVY4200	GaAsP on GaP	
Green	TLVG4200	GaP on GaP	

### Description

The TLV.4200 serie was developed for backlighting. Due to its special shape the spatial distribution of the radiation is qualified for backlighting.

To optimize the brightness of backlighting a custom-built reflector (with scattering) is required. Uniform illumination can be enhanced by covering the front of the reflector with diffusor material.

This is a flexible solution for backlighting different areas.

### Features

- High light output
- Wide viewing angle
- Categorized for luminous flux
- Available in red, yellow, green
- Tinted clear package
- Low power dissipation
- Low self heating
- Rugged design
- High reliability

### Applications

Backlighting of display panels, LCD displays, symbols on switches, keyboards, graphic boards and measuring scales  
Illumination of large areas e.g. dot matrix displays

**Absolute Maximum Ratings** $T_{amb} = 25^\circ C$ , unless otherwise specified**TLVH4200 ,TLVY4200 ,TLVG4200**

Parameter	Test Conditions	Type	Symbol	Value	Unit
Reverse voltage			$V_R$	6	V
DC forward current	$T_{amb} \leq 30^\circ C$		$I_F$	30	mA
Surge forward current	$t_p \leq 10 \mu s$		$I_{FSM}$	1	A
Power dissipation	$T_{amb} \leq 30^\circ C$		$P_V$	100	mW
Junction temperature			$T_j$	100	$^\circ C$
Operating temperature range			$T_{amb}$	-20 to +100	$^\circ C$
Storage temperature range			$T_{stg}$	-55 to +100	$^\circ C$
Soldering temperature	$t \leq 5 s$ , 2 mm from body		$T_{sd}$	260	$^\circ C$
Thermal resistance junction/ambient			$R_{thJA}$	700	K/W

**Optical and Electrical Characteristics** $T_{amb} = 25^\circ C$ , unless otherwise specified**High efficiency red (TLVH4200 )**

Parameter	Test Conditions	Type	Symbol	Min	Typ	Max	Unit
Luminous flux	$I_F = 15 \text{ mA}$		$\phi_V$	10	25		mlm
Dominant wavelength	$I_F = 10 \text{ mA}$		$\lambda_d$	612		625	nm
Peak wavelength	$I_F = 10 \text{ mA}$		$\lambda_p$		635		nm
Angle of half intensity	$I_F = 10 \text{ mA}$		$\phi$		$\pm 85$		deg
Forward voltage	$I_F = 20 \text{ mA}$		$V_F$		2.4	3	V
Reverse voltage	$I_R = 10 \mu A$		$V_R$	6	15		V
Junction capacitance	$V_R = 0 \text{ V}, f = 1 \text{ MHz}$		$C_j$		50		pF

**Yellow (TLVY4200 )**

Parameter	Test Conditions	Type	Symbol	Min	Typ	Max	Unit
Luminous flux	$I_F = 15 \text{ mA}$		$\phi_V$	10	20		mlm
Dominant wavelength	$I_F = 10 \text{ mA}$		$\lambda_d$	581		594	nm
Peak wavelength	$I_F = 10 \text{ mA}$		$\lambda_p$		585		nm
Angle of half intensity	$I_F = 10 \text{ mA}$		$\phi$		$\pm 85$		deg
Forward voltage	$I_F = 20 \text{ mA}$		$V_F$		2.4	3	V
Reverse voltage	$I_R = 10 \mu A$		$V_R$	6	15		V
Junction capacitance	$V_R = 0 \text{ V}, f = 1 \text{ MHz}$		$C_j$		50		pF

**Green (TLVG4200 )**

Parameter	Test Conditions	Type	Symbol	Min	Typ	Max	Unit
Luminous flux	$I_F = 15 \text{ mA}$		$\phi_V$	10	30		$\text{mlm}$
Dominant wavelength	$I_F = 10 \text{ mA}$		$\lambda_d$	562		575	$\text{nm}$
Peak wavelength	$I_F = 10 \text{ mA}$		$\lambda_p$		565		$\text{nm}$
Angle of half intensity	$I_F = 10 \text{ mA}$		$\varphi$		$\pm 85$		$\text{deg}$
Forward voltage	$I_F = 20 \text{ mA}$		$V_F$		2.4	3	$\text{V}$
Reverse voltage	$I_R = 10 \mu\text{A}$		$V_R$	6	15		$\text{V}$
Junction capacitance	$V_R = 0 \text{ V}, f = 1 \text{ MHz}$		$C_j$		50		$\text{pF}$

**Typical Characteristics** ( $T_{amb} = 25^{\circ}\text{C}$ , unless otherwise specified)

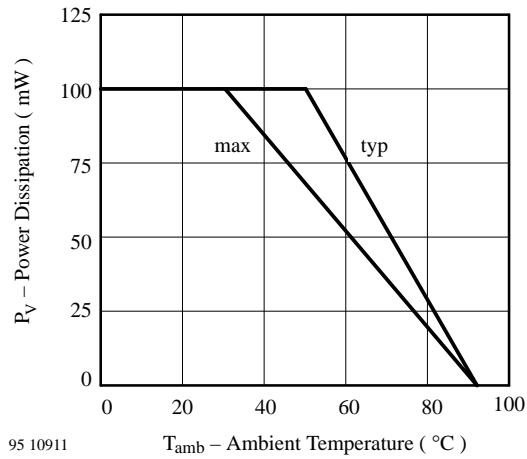


Figure 1. Power Dissipation vs. Ambient Temperature

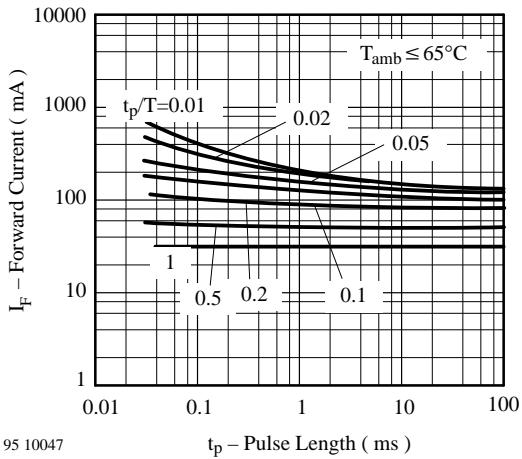


Figure 3. Forward Current vs. Pulse Length

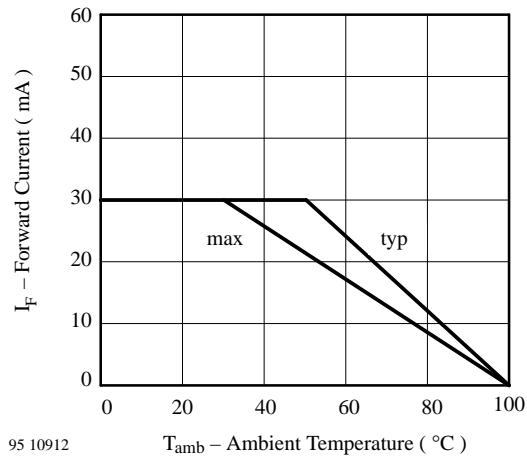


Figure 2. Forward Current vs. Ambient Temperature

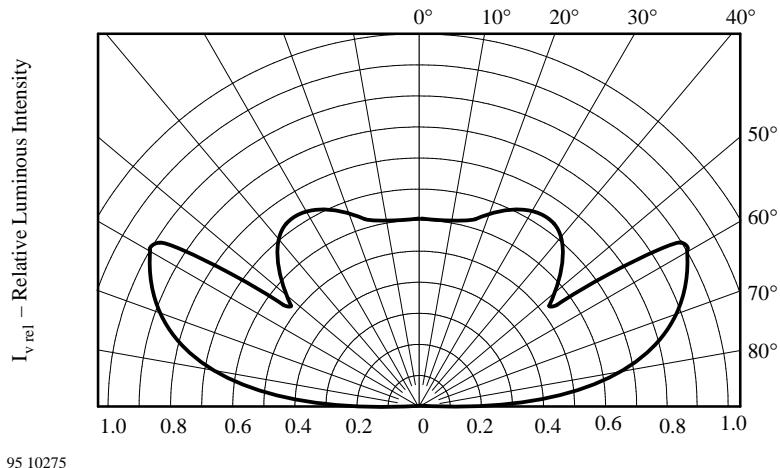
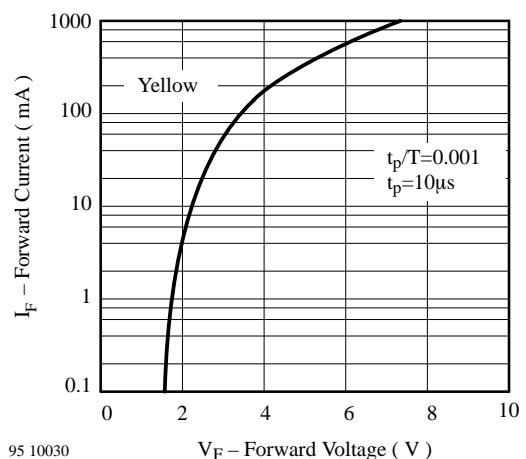
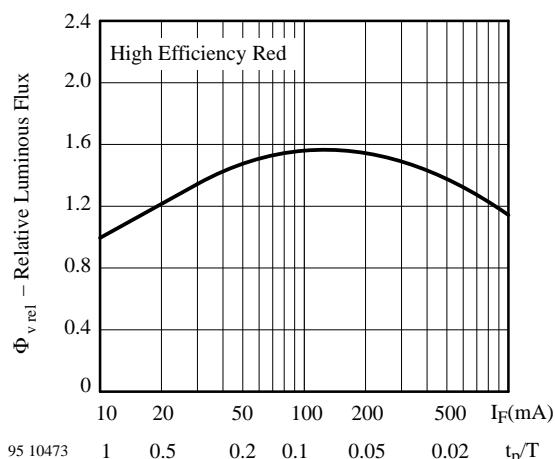
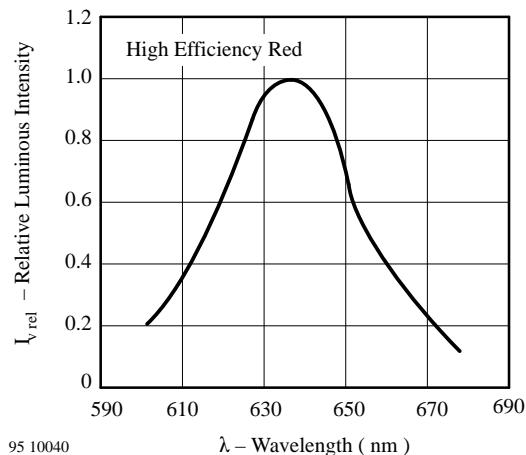
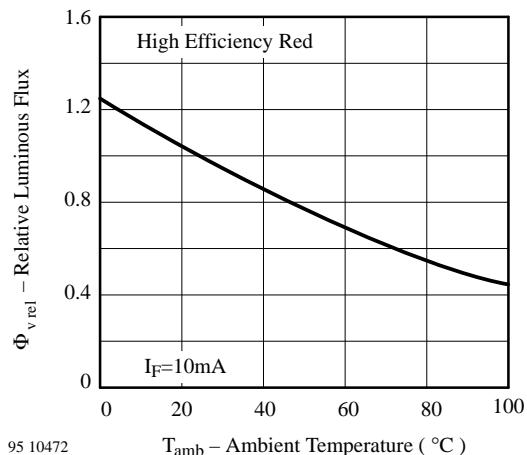
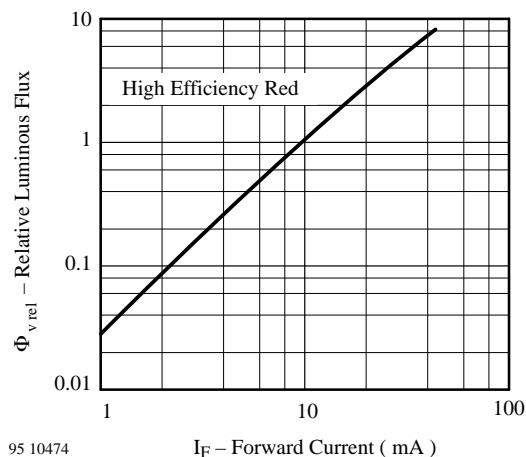
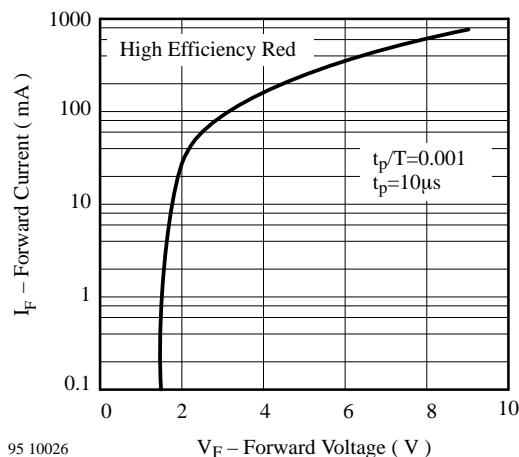


Figure 4. Rel. Luminous Intensity vs. Angular Displacement



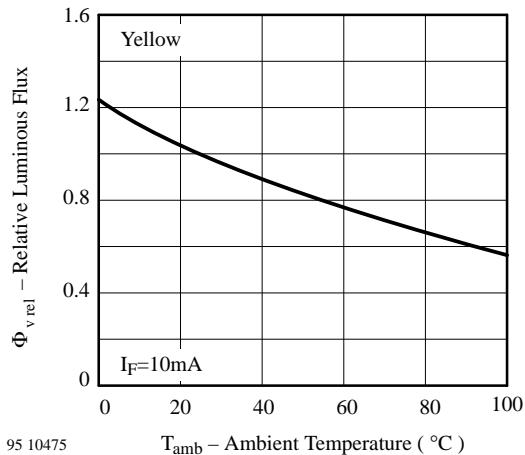


Figure 11. Rel. Luminous Flux vs. Ambient Temperature

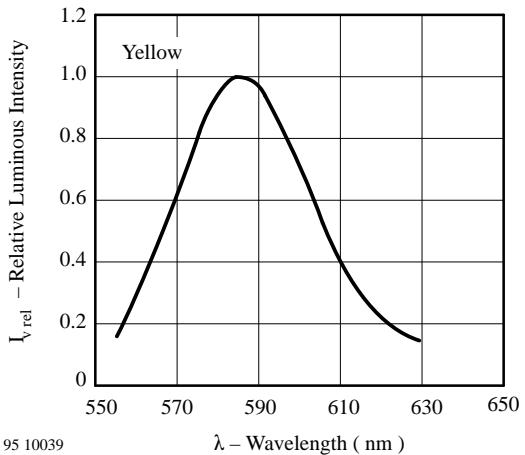


Figure 14. Relative Luminous Intensity vs. Wavelength

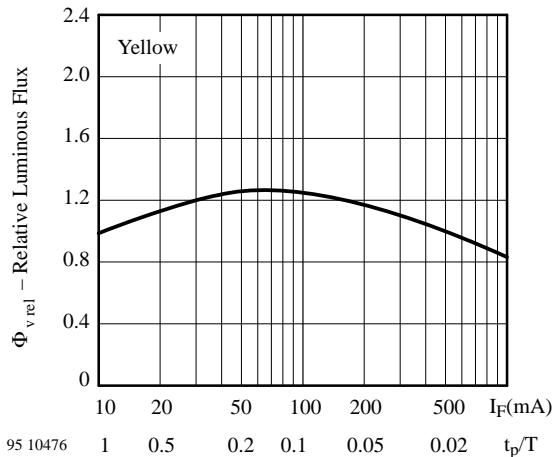


Figure 12. Rel. Luminous Flux vs. Forw. Current/Duty Cycle

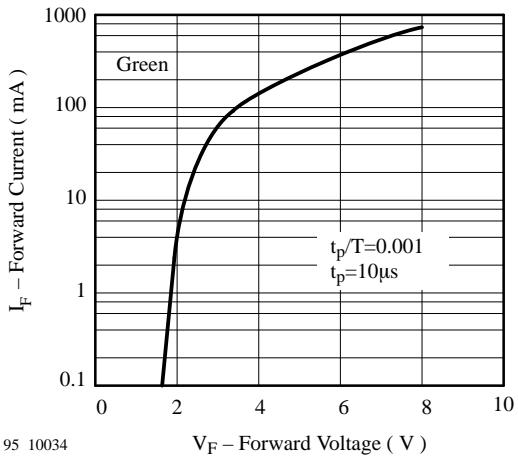


Figure 15. Forward Current vs. Forward Voltage

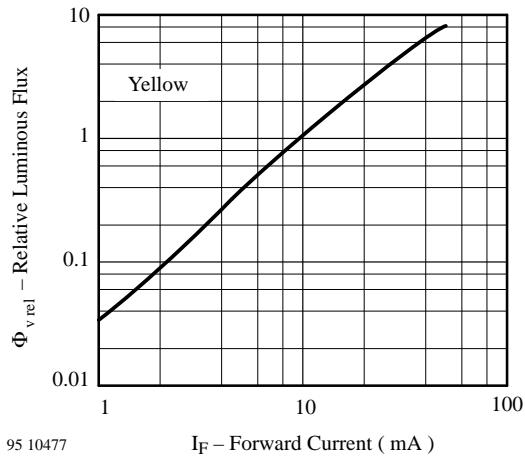


Figure 13. Relative Luminous Flux vs. Forward Current

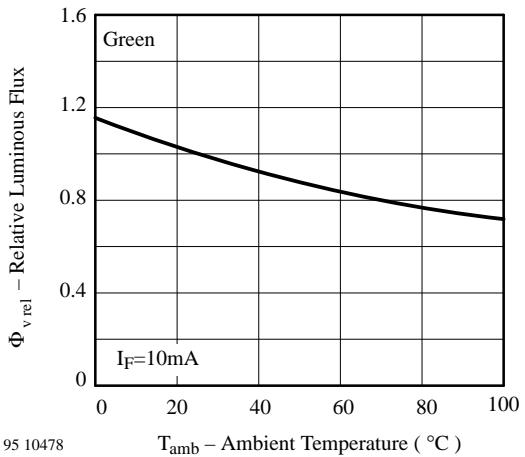


Figure 16. Rel. Luminous Flux vs. Ambient Temperature

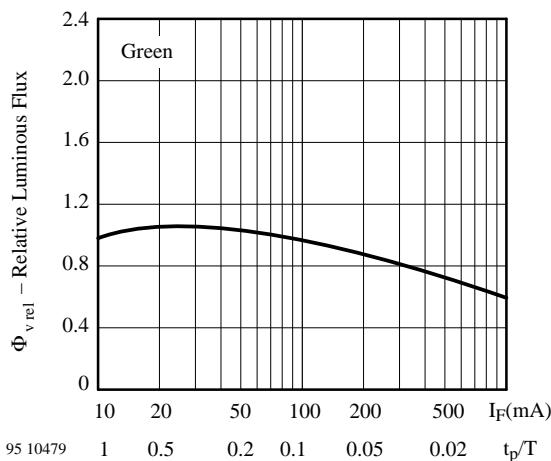


Figure 17. Rel. Luminous Flux vs. Forw. Current/Duty Cycle

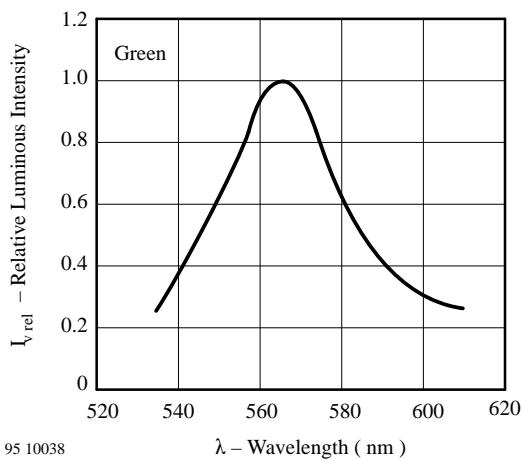


Figure 19. Relative Luminous Intensity vs. Wavelength

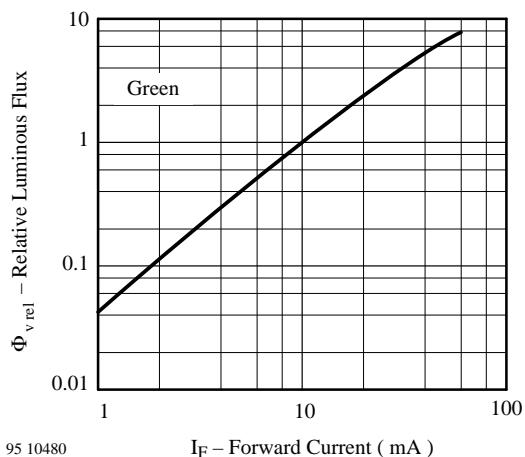
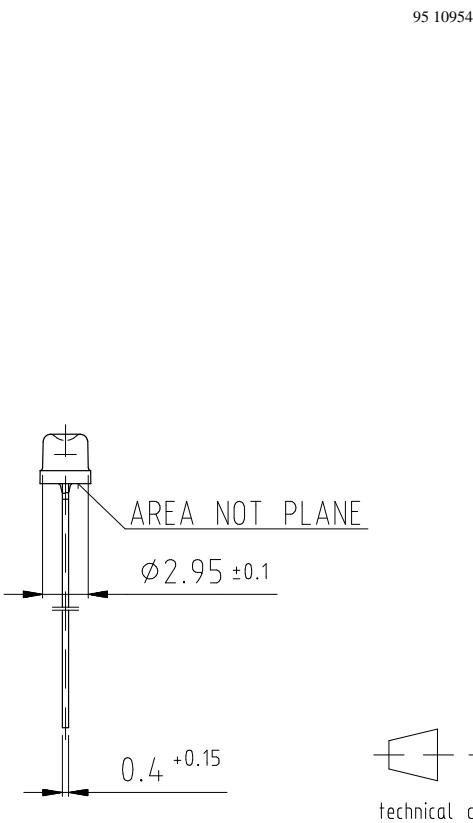
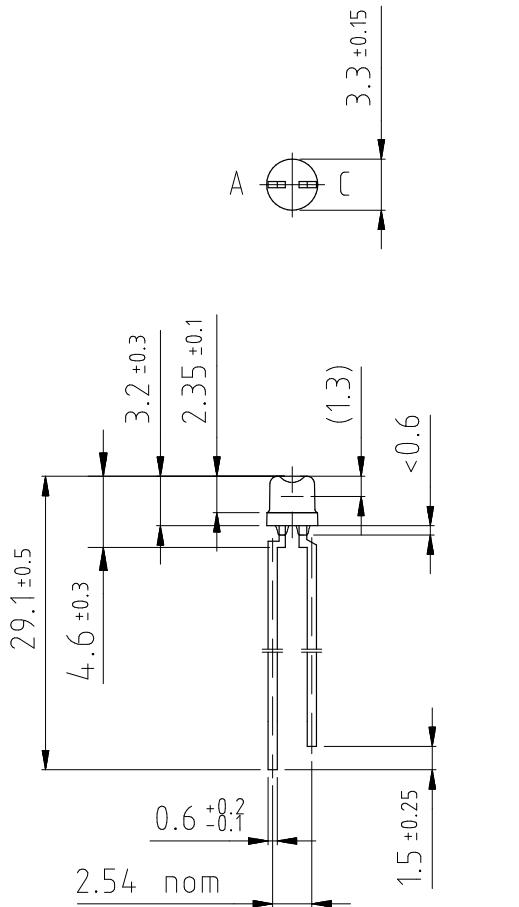


Figure 18. Relative Luminous Flux vs. Forward Current

## Dimensions in mm



technical drawings  
according to DIN  
specifications

## Ozone Depleting Substances Policy Statement

It is the policy of **TEMIC TELEFUNKEN microelectronic GmbH** to

1. Meet all present and future national and international statutory requirements.
2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

**TEMIC TELEFUNKEN microelectronic GmbH** semiconductor division has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

**TEMIC** can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

### We reserve the right to make changes to improve technical design and may do so without further notice.

Parameters can vary in different applications. All operating parameters must be validated for each customer application by the customer. Should the buyer use TEMIC products for any unintended or unauthorized application, the buyer shall indemnify TEMIC against all claims, costs, damages, and expenses, arising out of, directly or indirectly, any claim of personal damage, injury or death associated with such unintended or unauthorized use.

TEMIC TELEFUNKEN microelectronic GmbH, P.O.B. 3535, D-74025 Heilbronn, Germany  
Telephone: 49 (0)7131 67 2831, Fax number: 49 (0)7131 67 2423